

# Dual-Channel Audio Difference Amplifier

**Preliminary Technical Data** 

**AD8273** 

### **FEATURES**

Two gain settings:
Gain of 1/2 (-6 dB)
Gain of 2 (6 dB)
0.03% max gain accuracy
10 ppm max gain drift
Excellent AC Specifications
25V/µs slew rate

0.9 μs to 0.01% settling time

**Low Distortion** 

0.003% at 1 kHz

**High Accuracy DC Performance** 

90 dB typ CMRR

250 uV max offset voltage

14 lead SOIC Package

Supply current: 2.5 mA per channel

Supply range:  $\pm 2.5$  V to  $\pm 18$  V

#### **APPLICATIONS**

High Performance Audio
Instrumentation Amplifier Building Block
Level Translator
Automatic Test Equipment
Sin/Cos Encoders

#### **GENERAL DESCRIPTION**

The AD8273 is a low distortion, dual-channel amplifier with internal gain setting resistors. With no external components, it can be configured as a high performance difference amplifier (G=0.5 or 2), inverting amplifier (G=0.5 or 2) or non-inverting amplifier (G=1.5 or 3).

The AD8273 operates on both single and dual supplies and only requires 2.5 mA maximum supply current for both amplifiers. It is specified over the industrial temperature range of  $-40^{\circ}$ C to  $+85^{\circ}$ C and is fully RoHS compliant.

#### **FUNCTIONAL BLOCK DIAGRAM**

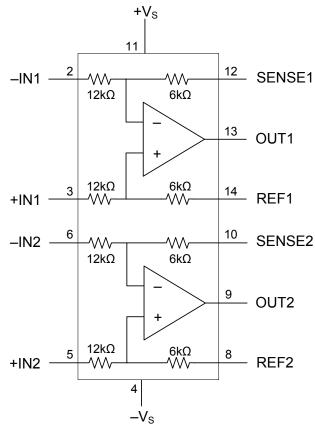


Figure 1. AD8273 Dual Difference Amplifier

Table 1. Difference Amplifiers by Category

Low Distortion	High Voltage	Single Supply Uni-directional	Single Supply Bi-directional
AD8270	AD628	AD8202	AD8205
AD8273	AD629	AD8203	AD8206
AMP03	AD8212		AD8210

# **AD8273**

# **SPECIFICATIONS**

 $V_{\text{S}}=\pm 18$  V,  $V_{\text{REF}}=0$  V,  $T_{\text{A}}=25^{\circ}\text{C},$  G=1/2,  $R_{\text{L}}=2$  k $\Omega,$  unless otherwise noted.

Table 2.

Parameter	Conditions	Min	Тур	Max	Unit
DYNAMIC PERFORMANCE					
Bandwidth			12		MHz
Slew Rate			25		V/µs
Settling Time to 0.1%	10V Step on output, C <sub>L</sub> =100 pF		0.7		μs
Settling Time to 0.01%	10V Step on output, C <sub>L</sub> =100 pF		0.9		μs
Channel Separation	f = 1 kHz		130		dB
NOISE/DISTORTION <sup>1</sup>					
THD + Noise	$f = 1 \text{ kHz}, V_{IN} = 10 \text{ Vrms}$		0.003		%
Noise Floor, RTO	20 kHz BW		-120		dBu <sup>2</sup>
Output Voltage Noise (referred to input)	f = 20 Hz to 20 kHz		3		μVrms
	f = 1 kHz		20		nV/√Hz
GAIN					
Gain Error				0.03	%
Gain Drift			1	10	ppm/°C
Gain Nonlinearity			10		ppm
INPUT CHARACTERISTICS					
Offset <sup>3</sup>			200	400	μV
vs. Temperature			2		μV/°C
vs. Power Supply			5	20	μV/V
Common Mode Rejection Ratio	$V_{CM}=\pm 18V$ , $R_S=0\Omega$ , referred to	77	86		dB
,	input				
Input Voltage Range		-Vs-0.5		+V <sub>s</sub> +0.5	V
Impedance					
Differential			24		kΩ
Common Mode⁴			9		kΩ
OUTPUT CHARACTERISTICS					
Output Swing		-Vs+1.5		+ V <sub>s</sub> -1.5	V
Short circuit current limit			60		mA
Capacitive Load Drive			100		pF
POWER SUPPLY					<u> </u>
Supply Current (per Amplifier)				2.5	mA
TEMPERATURE RANGE					1
Specified Performance		-40		85	
Specifica i criormanec	<u> </u>	10		0.5	1

 $<sup>^{1}</sup>$  Includes amplifier voltage noise, resistor network voltage noise, and amplifier current noise through resistor network  $^{2}$  dBu = 20log(Vrms/0.7746)

<sup>&</sup>lt;sup>3</sup> Includes effects of amplifier's input bias and offset currents

 $<sup>^4</sup>$  Calculated looking into both inputs. Common mode impedance looking into only one input is 18 k $\Omega$ 

# **Preliminary Technical Data**

## **ABSOLUTE MAXIMUM RATINGS**

Table 3.

Parameter	Rating		
Supply Voltage	TBD		
Output Short-Circuit Current	Indefinite		
Input Voltage (Common Mode)	TBD		
Differential Input Voltage	TBD		
Storage Temperature Range	−65°C to +130°C		
Specified Temperature Range	−40°C to +85°C		
Thermal Resistance $\theta_{JA}$	120 °C/W		
Thermal Resistance $\theta_{JC}$	36 °C/W		
Package Glass Transition Temperature $(T_G)$	130°C		

Stresses above those listed under Absolute Maximum Ratings may cause permanent damage to the device. This is a stress rating only; functional operation of the device at these or any other conditions above those indicated in the operational section of this specification is not implied. Exposure to absolute maximum rating conditions may affect device reliability.

## **Maximum Power Dissipation**

The maximum safe power dissipation for the AD8273 is limited by the associated rise in junction temperature  $(T_l)$  on the die. At approximately 130°C, which is the glass transition temperature, the plastic changes its properties. Even temporarily exceeding this temperature limit may change the stresses that the package exerts on the die, permanently shifting the parametric performance of the amplifiers. Exceeding a temperature of 130°C for an extended period can result in a loss of functionality.

## **ESD CAUTION**

ESD (electrostatic discharge) sensitive device. Electrostatic charges as high as 4000 V readily accumulate on the human body and test equipment and can discharge without detection. Although this product features proprietary ESD protection circuitry, permanent damage may occur on devices subjected to high energy electrostatic discharges. Therefore, proper ESD precautions are recommended to avoid performance degradation or loss of functionality.

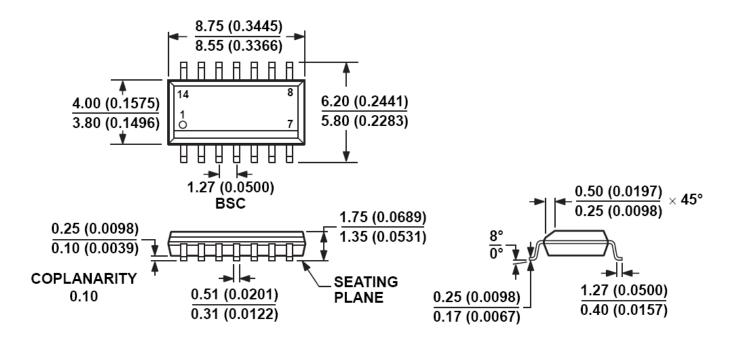


## **OUTLINE DIMENSIONS**



14-Lead Standard Small Outline Package [SOIC\_N]
Narrow Body
(R-14)

Dimensions shown in millimeters and (inches)



## **COMPLIANT TO JEDEC STANDARDS MS-012-AB**

Figure 2. 14 Lead Narrow Body SOIC package